

RECEIVED  
CENTRAL FAX CENTER

DEC 8 9 2003

19496600809

# 3/ 7

Application No.: 10/015,414

Docket No.: JCLA7737

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of :  
Application No. : 10/015,414  
Filed : December 12, 2001  
For : Method For Programming And Erasing Non-Volatile Memory With  
Nitride Tunneling Layer  
Applicant : Tso-Hung Fan  
Examiner : Pham, Ly D  
Art Unit : 2818

---

PRELIMINARY AMENDMENT

Commissioner for Patents  
P. O. Box 1450  
Alexandria, VA 22313-1450

Sir:

The Advisory Office Action mailed December 8, 2003 has been carefully considered. In response thereto, please enter the following amendments for RCE and consider the following remarks.

Page 1 of 5